



60V N-Channel Enhancement Mode MOSFET

Voltage

60 V

Current

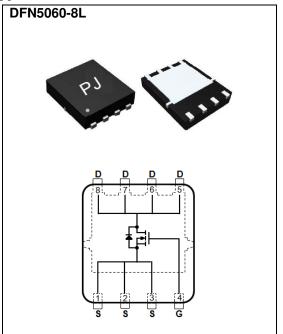
42 A

Features

- $R_{DS(ON)}$, V_{GS} @10V, I_{D} @20A<12m Ω
- $R_{DS(ON)}$, $V_{GS}@4.5V$, $I_{D}@10A<15m\Omega$
- High switching speed
- Low reverse transfer capacitance
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case: DFN5060-8L Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0028 ounces, 0.08 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

| PARAMETER | | SYMBOL | LIMIT | UNITS | |
|--|-----------------------|-----------------|-------------|-------|--|
| Drain-Source Voltage | | V_{DS} | 60 | W | |
| Gate-Source Voltage | | V_{GS} | <u>+</u> 20 | V | |
| Continuous Drain Current (Note 4) | T _C =25°C | l _D | 42 | А | |
| | T _C =100°C | | 26 | | |
| Pulsed Drain Current (Note 1) | T _C =25°C | I _{DM} | 84 | | |
| Power Dissipation | T _C =25°C | - | 71.4 | 14/ | |
| | $T_C=100^{\circ}C$ | Pb | 35.7 | W | |
| Continuous Drain Current (Note 4) | T _A =25°C | | 8.5 | | |
| | T _A =70°C | l _D | 6.8 | Α | |
| Power Dissipation | T _A =25°C | - | 2.4 | W | |
| | T _A =70°C | Po | 1.6 | | |
| Single Pulse Avalanche Energy (Note 6) | | E _{AS} | 72 | mJ | |
| Operating Junction and Storage Temperature Range | | T_J, T_{STG} | -55~175 | °C | |
| Typical Thermal Resistance (Note 4,5) | Junction to Case | $R_{	heta JC}$ | 2.1 | °C/W | |
| | Junction to Ambient | $R_{\theta JA}$ | 62.5 | | |

Limited only By Maximum Junction Temperature





Electrical Characteristics (T_A=25°C unless otherwise noted)

| PARAMETER | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNITS |
|----------------------------------|---------------------|--|------|------|--------------|-------|
| Static | | | • | • | • | |
| Drain-Source Breakdown Voltage | BV_{DSS} | V _{GS} =0V, I _D =250uA | 60 | - | - | V |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{DS}=V_{GS}$, $I_{D}=250uA$ | 1 | 1.7 | 2.5 | |
| Drain-Source On-State Resistance | R _{DS(on)} | V _{GS} =10V ,I _D =20A | - | 10 | 12 | mΩ |
| | | V_{GS} =4.5V, I_{D} =10A | - | 11 | 15 | |
| Zero Gate Voltage Drain Current | I_{DSS} | V_{DS} =60V, V_{GS} =0V | - | - | 1 | uA |
| Gate-Source Leakage Current | I_{GSS} | $V_{GS} = \pm 20V, V_{DS} = 0V$ | - | - | <u>+</u> 100 | nA |
| Dynamic (Note 7) | | | | | | |
| Total Gate Charge | Q_g | V _{DS} =30V, I _D =10A, V _{GS} =10V ^(Note 2,3) | - | 40 | - | nC |
| Gate-Source Charge | Q_gs | | - | 6.0 | - | |
| Gate-Drain Charge | Q_{gd} | | - | 7.2 | - | |
| Input Capacitance | Ciss | V _{DS} =25V, V _{GS} =0V, | - | 2142 | - | pF |
| Output Capacitance | Coss | | - | 149 | - | |
| Reverse Transfer Capacitance | Crss | f=1MHZ | - | 86 | - | |
| Turn-On Delay Time | td _(on) | V_{DD} =15V, I_{D} =10A, V_{GS} =10V, R_{G} =6 Ω (Note 2,3) | - | 14 | - | |
| Turn-On Rise Time | t _r | | - | 25 | - | ns |
| Turn-Off Delay Time | td _(off) | | - | 58 | - | |
| Turn-Off Fall Time | t _f | | - | 18 | - | |
| Drain-Source Diode | | | | | | |
| Maximum Continuous Drain-Source | | | - | - | 42 | А |
| Diode Forward Current | I _S | | | | | |
| Diode Forward Voltage | V_{SD} | I _S =1A, V _{GS} =0V | - | 0.67 | 1 | V |

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 4. The maximum current rating is package limited.
- 5. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. The test condition is L=0.5mH, I_{AS} =17A, V_{DD} =25V, V_{GS} =10V
- 7. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

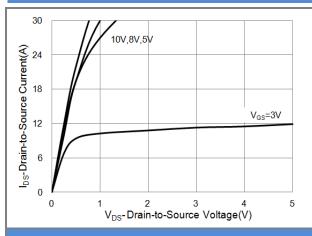


Fig.1 Output Characteristics

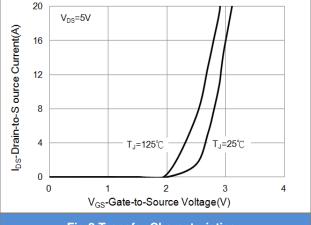


Fig.2 Transfer Characteristics

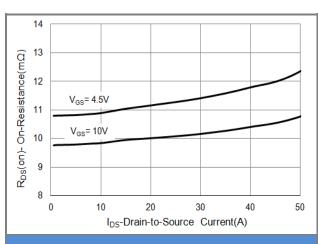


Fig.3 On-Resistance vs. Drain Current

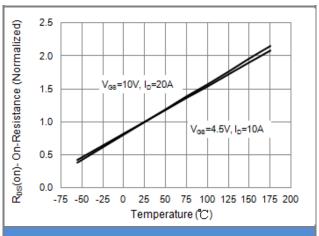
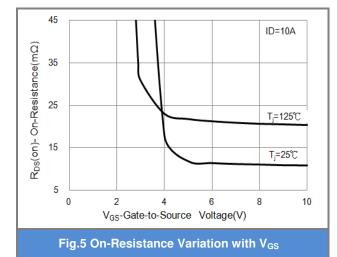


Fig.4 On-Resistance vs. Junction temperature



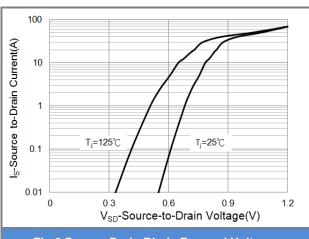


Fig.6 Source-Drain Diode Forward Voltage





TYPICAL CHARACTERISTIC CURVES

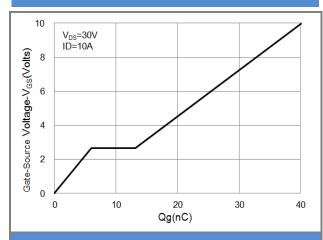
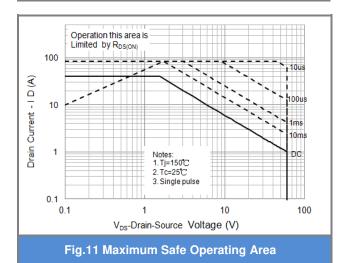


Fig.7 Gate-Charge Characteristics



Fig.9 Threshold Voltage Variation with Temperature

Temperature (℃)



1.1 l_{p=250uA}

1.1 l_{p=250uA}

1.0 l_{p=250uA}

0.9 l_{p=250uA}

0.9 l_{p=250uA}

0.9 l_{p=250uA}

0.9 l_{p=250uA}

Temperature (°C)

Fig.8 Breakdown Voltage Variation vs. Temperature

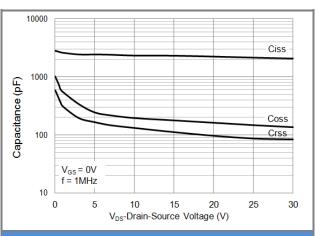


Fig.10 Capacitance vs. Drain-Source Voltage





TYPICAL CHARACTERISTIC CURVES

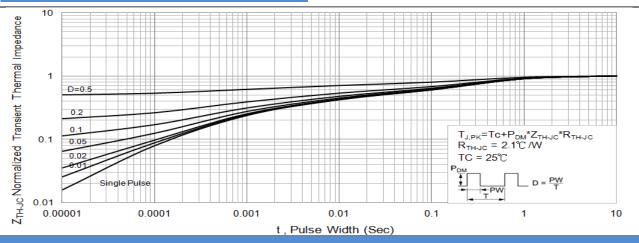


Fig.12 Normalized Transient Thermal Impedance vs. Pulse Width

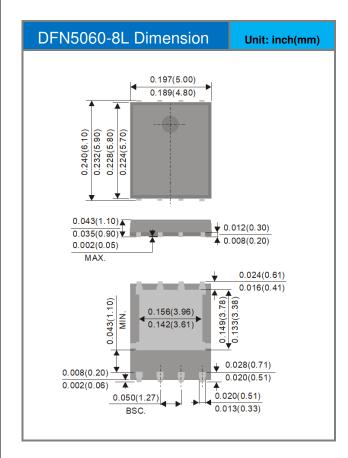


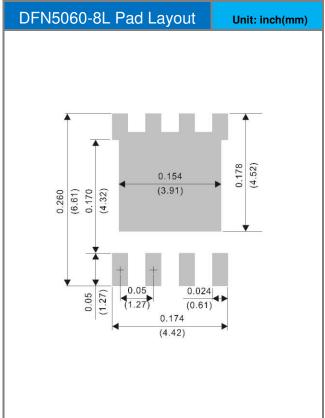


Part No Packing Code Version

| Part No Packing Code | Package Type | Packing Type | Marking | Version | |
|----------------------|--------------|--------------------|---------|--------------|--|
| PJQ5462A-AU_R2_000A1 | DFN5060-8L | 3000pcs / 13" reel | Q5462A | Halogen free | |

Packaging Information & Mounting Pad Layout









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